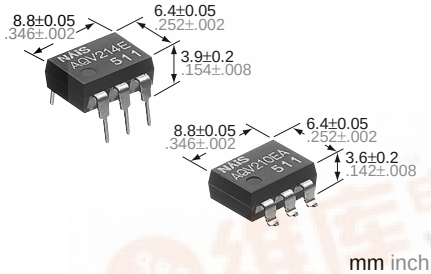
(Standard type) (Reinforced type)

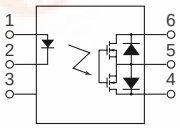
NAiS

GU (General Use)-E Type [1-Channel (Form A) Type]

PhotoMOS RELAYS



mm inch



FEATURES

1. Controls low-level analog signals
PhotoMOS relays feature extremely low closed-circuit offset voltage to enable control of low-level analog signals without distortion.

2. Control with low-level input signals

3. Controls various types of loads such as relays, motors, lamps and solenoids.

4. Optical coupling for extremely high isolation
Unlike mechanical relays, the PhotoMOS relay combines LED and optoelectronic device to transfer signals using light for extremely high isolation.

5. Eliminates the need for a counter electromotive force protection diode in the drive circuits on the input side

6. Stable on resistance

7. Low-level off state leakage current

8. Eliminates the need for a power supply to drive the power MOSFET
A power supply used to drive the power MOSFET is unnecessary because of the built-in optoelectronic device. This results in easy circuit design and small PC board area.

9. Low thermal electromotive force (Approx. 1 μV)

TYPICAL APPLICATIONS

- High-speed inspection machines
- Telephone equipment
- Data communication equipment
- Computer

TYPES

Type	I/O isolation	Output rating*		Part No.				Packing quantity	
				Through hole terminal	Surface-mount terminal				
		Load voltage	Load current	Tube packing style		Tape and reel packing style		Tube	Tape and reel
						Picked from the 1/2/3-pin side	Picked from the 4/5/6-pin side		
AC/DC	Standard 1,500 V AC	350 V	130 mA	AQV210E	AQV210EA	AQV210EAX	AQV210EAZ	1 tube contains 50 pcs. 1 batch contains 500 pcs.	1,000 pcs.
		400 V	120 mA	AQV214E	AQV214EA	AQV214EAX	AQV214EAZ		
	Reinforced 5,000 V	350 V	130 mA	AQV210EH	AQV210EHA	AQV210EHAX	AQV210EHAZ		
		400 V	120 mA	AQV214EH	AQV214EHA	AQV214EHAX	AQV214EHAZ		

*Indicate the peak AC and DC values.
Note: For space reasons, the package type indicator "X" and "Z" are omitted from the seal.

RATING

1. Absolute maximum ratings (Ambient temperature: 25°C 77°F)

Item		Sym-bol	Type of connec-tion	AQV210E(A)	AQV214E(A)	AQV210EH(A)	AQV214EH(A)	Remarks
Input	LED forward current	I_F		50 mA				
	LED reverse voltage	V_R		3 V				
	Peak forward current	I_{FP}		1 A				f = 100 Hz, Duty factor = 0.1%
	Power dissipation	P_{in}		75 mW				
Output	Load voltage (peak AC)	V_L		350 V	400 V	350 V	400 V	
	Continuous load current	I_L	A	0.13 A	0.12 A	0.13 A	0.12 A	A connection: Peak AC, DC; B, C connection: DC
			B	0.15 A	0.13 A	0.15 A	0.13 A	
			C	0.17 A	0.15 A	0.17 A	0.15 A	
	Peak load current	I_{peak}		0.4 A	0.3 A	0.4 A	0.3 A	A connection: 100 ms (1 shot), V_L=DC
	Power dissipation	P_{out}		500 mW				
Total power dissipation		P_T		550 mW				
I/O isolation voltage		V_{iso}		1,500 V AC		5,000 V AC		
Temperature limits	Operating	T_{opr}		–40°C to +85°C –40°F to +185°F				Non-condensing at low temp.
	Storage	T_{stg}		–40°C to +100°C –40°F to +212°F				

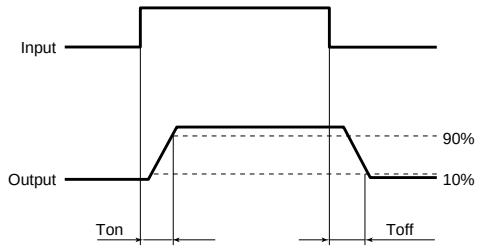
2. Electrical characteristics (Ambient temperature: 25°C 77°F)

Item				Sym-bol	Type of connec-tion	AQV210E(A)	AQV214E(A)	AQV210EH(A)	AQV214EH(A)	Condition
Input	LED operate current		Typical	I_{Fon}	—	1.1 mA	1.1 mA	1.6 mA	1.6 mA	I_L = Max.
			Maximum			3 mA				
	LED turn off current		Minimum	I_{Foff}	—	0.3 mA	0.3 mA	0.4 mA	0.4 mA	I_L = Max.
			Typical			1.0 mA	1.0 mA	1.5 mA	1.5 mA	
	LED dropout voltage		Typical	V_F	—	1.14 V (1.25 V at I_F = 50 mA)				I_F = 5 mA
			Maximum			1.5 V				
Output	On resistance		Typical	R_{on}	A	23 Ω	30 Ω	23 Ω	30 Ω	I_F = 5 mA I_L = Max. Within 1 s on time
			Maximum			35 Ω	50 Ω	35 Ω	50 Ω	
			Typical	R_{on}	B	11.5 Ω	22.5 Ω	11.5 Ω	22.5 Ω	I_F = 5 mA I_L = Max. Within 1 s on time
			Maximum			17.5 Ω	25 Ω	17.5 Ω	25 Ω	
			Typical	R_{on}	C	6.0 Ω	11.3 Ω	6.0 Ω	11.3 Ω	I_F = 5 mA I_L = Max. Within 1 s on time
			Maximum			8.8 Ω	12.5 Ω	8.8 Ω	12.5 Ω	
	Output capacitance		Typical	C_{out}	A	45 pF				I_F = 0 V_B = 0 f = 1 MHz
	Off state leakage current		Maximum	—	—	1 μA				I_F = 0 V_L = Max.
Transfer characteristics	Switching speed	Turn on time*	Typical	T_{on}	—	0.5 ms	0.5 ms	0.7 ms	0.7 ms	I_F= 5 mA** I_L=Max.
			Maximum			2.0 ms	2.0 ms	2.0 ms	2.0 ms	
		Turn off time*	Typical	T_{off}	—	0.05 ms				I_F = 5 mA I_L = Max.
			Maximum			1.0 ms				
	I/O capacitance		Typical	C_{iso}	—	0.8 pF				f = 1 MHz V_B = 0
			Maximum			1.5 pF				
	Initial I/O isolation resistance		Minimum	R_{iso}	—	1,000 MΩ				500 V DC

Note: Recommendable LED forward current
Standard type: 5 mA
Reinforced type: 5 to 10 mA

For type of connection, see page 31.

*Turn on/Turn off time

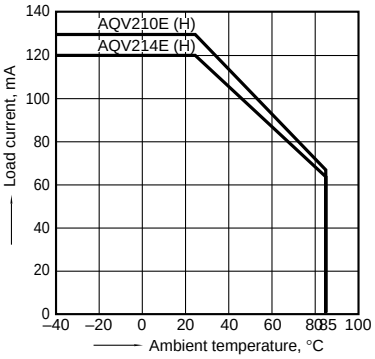


REFERENCE DATA

1. Load current vs. ambient temperature characteristics

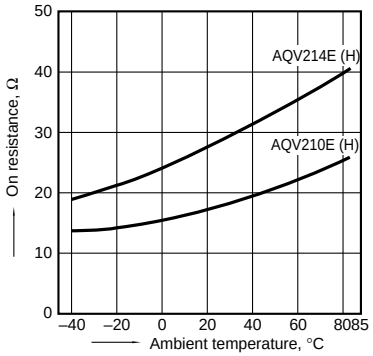
Allowable ambient temperature: –40°C to +85°C
–40°F to +185°F

Type of connection:A



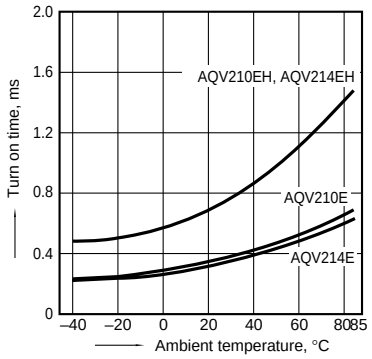
2. On resistance vs. ambient temperature characteristics

Measured portion: between terminals 4 and 6;
LED current: 5 mA; Load voltage: Max. (DC);
Continuous load current: Max. (DC)



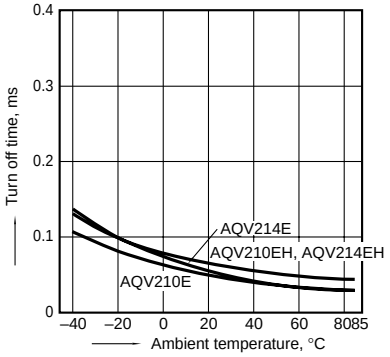
3. Turn on time vs. ambient temperature characteristics

LED current: 5 mA;
Load voltage: Max. (DC);
Continuous load current: Max. (DC)



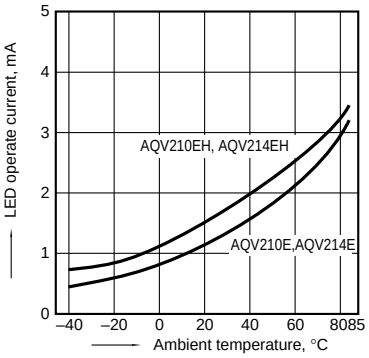
4. Turn off time vs. ambient temperature characteristics

LED current: 5 mA; Load voltage: Max. (DC);
Continuous load current: Max. (DC)



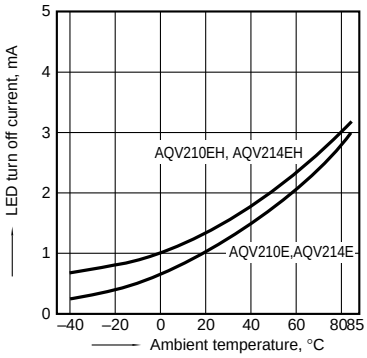
5. LED operate current vs. ambient temperature characteristics

Load voltage: Max. (DC);
Continuous load current: Max. (DC)



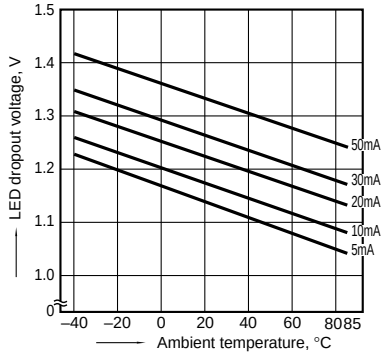
6. LED turn off current vs. ambient temperature characteristics

Load voltage: Max. (DC);
Continuous load current: Max. (DC)



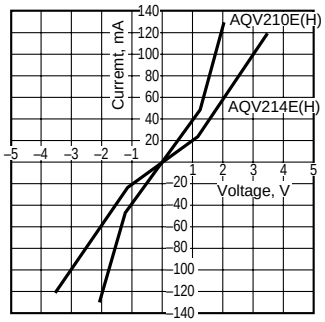
7. LED dropout voltage vs. ambient temperature characteristics

Sample: All types
LED current: 5 to 50 mA



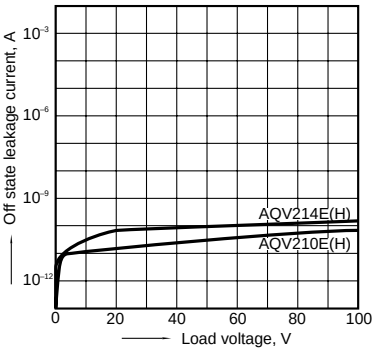
8. Voltage vs. current characteristics of output at MOS portion

Measured portion: between terminals 4 and 6;
Ambient temperature: 25°C 77°F



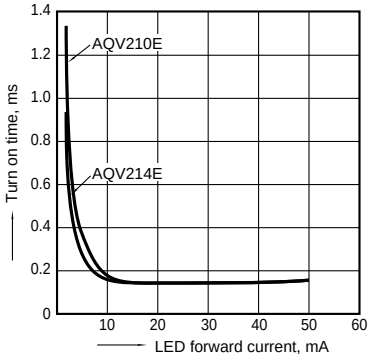
9. Off state leakage current

Measured portion: between terminals 4 and 6;
Ambient temperature: 25°C 77°F



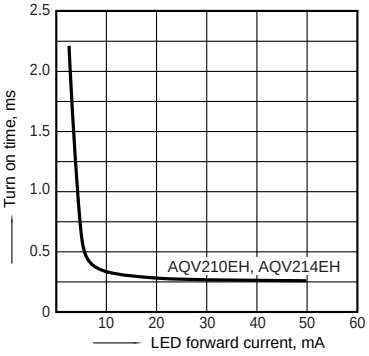
10-(1). LED forward current vs. turn on time characteristics

Measured portion: between terminals 4 and 6;
Load voltage: Max. (DC); Continuous load current:
Max. (DC); Ambient temperature: 25°C 77°F



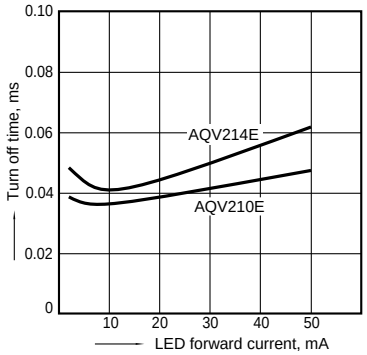
10-(2). LED forward current vs. turn on time characteristics

Measured portion: between terminals 4 and 6;
Load voltage: Max. (DC); Continuous load current:
Max. (DC); Ambient temperature: 25°C 77°F



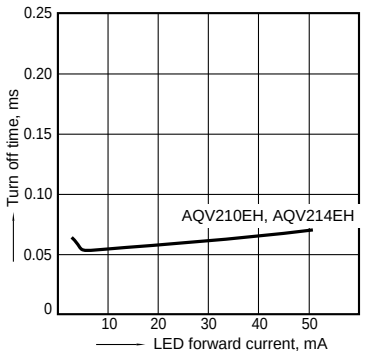
11-(1). LED forward current vs. turn off time characteristics

Measured portion: between terminals 4 and 6;
Load voltage: Max. (DC); Continuous load current:
Max. (DC); Ambient temperature: 25°C 77°F



11-(2). LED forward current vs. turn off time characteristics

Measured portion: between terminals 4 and 6;
Load voltage: Max. (DC); Continuous load current:
Max. (DC); Ambient temperature: 25°C 77°F



12. Applied voltage vs. output capacitance characteristics

Measured portion: between terminals 4 and 6;
Frequency: 1 MHz;
Ambient temperature: 25°C 77°F